



12-22-05

DFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Serial No.: 10/677,005  
Applicant: Jer-shen Maa *et al.*  
Filed: September 30, 2003  
Group #: 1763  
Examiner: George A. Goudreau

Confirmation Number: 7276

Docket No: SLA.0780  
Customer No: 55376  
For: Method of Making Relaxed Silicon-Germanium on Insulator via Layer Transfer  
with Stress Reduction

MS AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

**RESPONSE TO OFFICE ACTION UNDER 37 C.F.R. § 1.111**  
**Change of Correspondence Address**  
**Introductory Comments**

In response to the Office Action dated October 4, 2005, please amend the above-identified Application as follows:

**Amendment to the Specification** None

**Amendment to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Amendment to the Drawings** None

**Remarks/Arguments** begin on page 8 of this paper.

An **Appendix** is not included.